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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR $\mu PA2352$

Dual N-CHANNEL MOSFET

DESCRIPTION

The $\mu {\rm PA2352}$ is a Dual N-channel MOSFET designed for Lithium-lon battery protection circuit.

Ecologically Flip chip MOSFET for Lithium-Ion battery Protection (EFLIP).

FEATURES

- Monolithic Dual MOSFET
 - Connecting the Drains on the circuit board is not required because the Drains of the FET1 and the FET2 are internally connected.
- 2.5 V drive available and low on-state resistance

Rss(on)1 = 43.0 m Ω MAX. (Vgs = 4.5 V, Is = 2.0 A)

Rss(on)2 = 45.0 m Ω MAX. (Vgs = 4.0 V, Is = 2.0 A)

Rss(on)3 = 55.0 m Ω MAX. (Vgs = 3.1 V, Is = 2.0 A)

Rss(on)4 = 67.0 m Ω MAX. (Vgs = 2.5 V, Is = 2.0 A)

- Built-in G-S protection diode against ESD
- · Pb-free bump

ORDERING INFORMATION

PART NUMBER	PACKAGE	
μPA2352T1G-E4-A Note	4 PIN EFLIP	

Note "-A" indicates Pb-free (This product does not contain Pb in external electrode and other parts)."-E4" indicates the unit orientation (-E4 only).

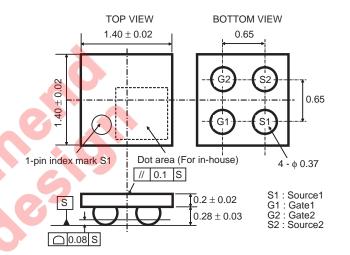
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Source to Source Voltage (Vgs = 0 V)	Vsss	24	V	
Gate to Source Voltage (Vss = 0 V)	Vgss	±12	V	
Source Current (DC) Note1	Is(DC)	±4.0	Α	
Source Current (pulse) Note2	S(pulse)	±40	Α	
Total Power Dissipation (2units) Note1	Рт	0.75	W	
Channel Temperature	Tch	150	°C	
Storage Temperature	T_{stg}	-55 to +150	°C	

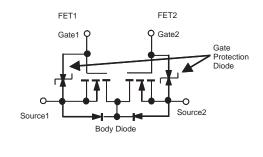
Notes 1. Mounted on BT resin board of 40.5 mm x 25 mm x 1.5 mm

2. PW \leq 100 μ s, Duty Cycle \leq 1%

OUTLINE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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Document No.
Date Published
Printed in Japan

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G17881EJ2V0DS00 (2nd edition) October 2006 NS CP(K)

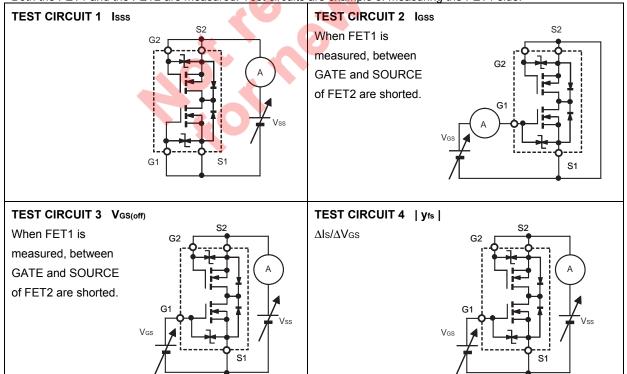
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ELECTRICAL CHARACTERISTICS (TA = 25°C)

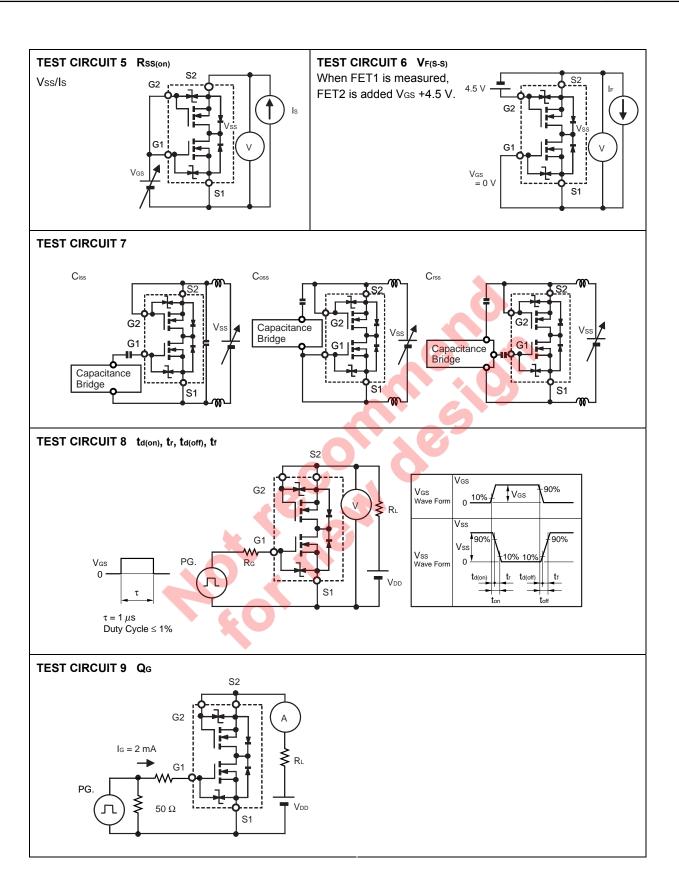
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Source Current	Isss	Vss = 24.0 V, Vss = 0 V, TEST CIRCUIT 1			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±12.0 V, V _{SS} = 0 V, TEST CIRCUIT 2			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	Vss = 10.0 V, Is = 1.0 mA, TEST CIRCUIT 3	0.5	1.0	1.5	V
Forward Transfer Admittance Note	yfs	Vss = 10.0 V, Is = 2.0 A, TEST CIRCUIT 4	2.5			S
Source to Source On-state	Rss(on)1	V _{GS} = 4.5 V, I _S = 2.0 A, TEST CIRCUIT 5	24.0	35.0	43.0	mΩ
Resistance Note	Rss(on)2	V _{GS} = 4.0 V, I _S = 2.0 A, TEST CIRCUIT 5	25.0	37.0	45.0	mΩ
	Rss(on)3	V _{GS} = 3.1 V, I _S = 2.0 A, TEST CIRCUIT 5	31.5	42.0	55.0	mΩ
	Rss(on)4	V _{GS} = 2.5 V, I _S = 2.0 A, TEST CIRCUIT 5	33.5	50.0	67.0	mΩ
Input Capacitance	Ciss	Vss = 10.0 V, Vss = 0 V, f = 1.0 MHz		330		pF
Output Capacitance	Coss	TEST CIRCUIT 7		80		pF
Reverse Transfer Capacitance	Crss			55		pF
Turn-on Delay Time	t _{d(on)}	Is = 4.0 A, V _{GS} = 4.0 V, V _{DD} = 20.0 V,		22		ns
Rise Time	tr	$R_G = 6.0 \Omega$, TEST CIRCUIT 8		132		ns
Turn-off Delay Time	t _{d(off)}			183		ns
Fall Time	tr			216		ns
Gate to Source Charge	Q _G	V _{G1S1} = 4.0 V, I _S = 4.0 A, V _{DD} = 20.0 V,		5.7		nC
		TEST CIRCUIT 9				
Body Diode Forward Voltage Note	V _{F(S-S)}	I _F = 4.0 A, V _{GS} = 0 V, TEST CIRCUIT 6		1.0		V

Note Pulsed

Both the FET1 and the FET2 are measured. Test circuits are example of measuring the FET1 side.



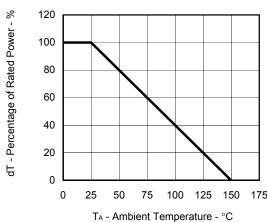
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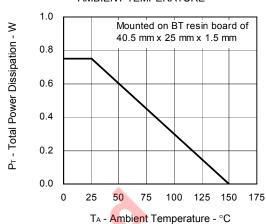
3

TYPICAL CHARACTERISTICS (TA = 25°C)

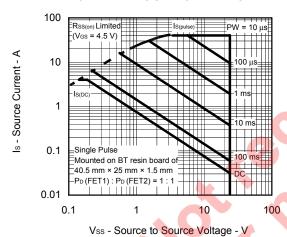
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



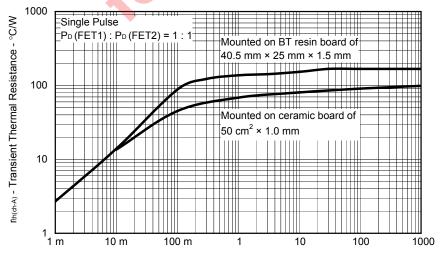
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



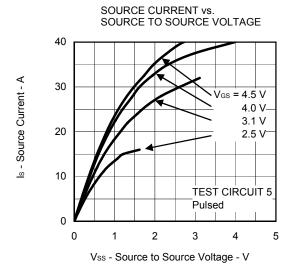
<R> FORWARD BIAS SAFE OPERATING AREA

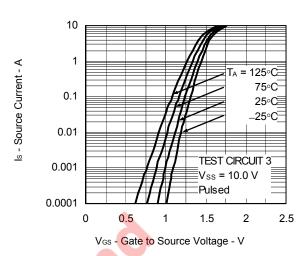




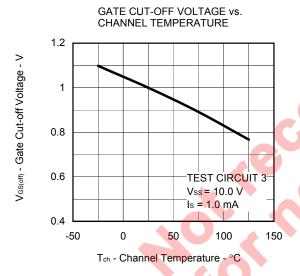


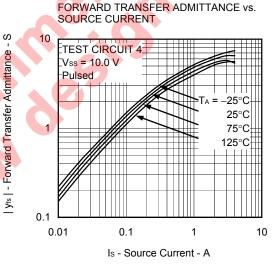
PW - Pulse Width - s

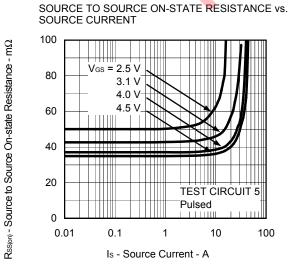


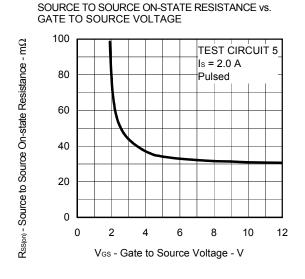


FORWARD TRANSFER CHARACTERISTICS





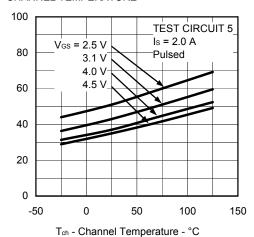




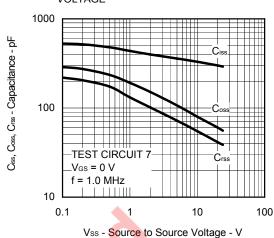
 $\mathsf{Rss}_{(m)}$ - Source to Source On-state Resistance - $m\Omega$

td(on), tr, td(off), tr - Switching Time - ns

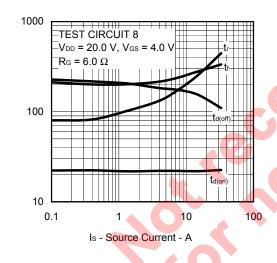
SOURCE TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



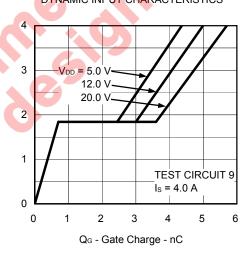
<R> CAPACITANCE vs. SOURCE TO SOURCE VOLTAGE



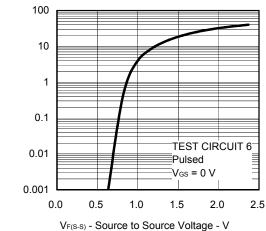
SWITCHING CHARACTERISTICS



DYNAMIC INPUT CHARACTERISTICS



SOURCE TO SOURCE DIODE FORWARD VOLTAGE



IF - Diode Forward Current - A

Source to Source Voltage - V

<Notes for using this device safely>

When you use this device, in order to prevent a customer's hazard and damage, use it with understanding the following contents. If used exceeding recommended conditions, there is a possibility of causing the device and characteristic degradation.

- 1. This device is very thin device and should be handled with caution for mechanical stress. The rate of distortion applied to the device should become below 2000 $\mu\epsilon$. If the rate of distortion exceeds 2000 $\mu\epsilon$, the characteristic of a device may be degraded and it may result in failure.
- 2. Please do not damage the device when you handle it. The use of metallic tweezers has the possibility of giving the wound. And mounting with the nozzle with clean point is recommended.
- 3. When you mount the device on a substrate, carry out within our recommended soldering conditions of infrared reflow. If mounted exceeding the conditions, the characteristic of a device may be degraded and it may result failure.
- 4. When you wash the device mounted the board, carry out within our recommended conditions. If washed exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
- 5. When you use ultrasonic wave to substrate after the device mounting, prevent from touching a resonance directly. If it touches, the characteristic of a device may be degraded and it may result in failure.
- 6. When you coat the device after mounted on the board, please consult our company. NEC Electronics recommends the epoxy resin of the semiconductor grade as a coating material.
- 7. Please refer to Figure 2 as an example of the Mounting Pad. Optimize the land pattern in consideration of density, appearance of solder fillets, common difference, etc in an actual design.
- 8. The marking side of this device is an internal electrode. Please neither contact with terminals of other parts nor take out the electrode.

Figure 1 Recommended soldering conditions of INFRARED REFLOW

Maximum temperature (Package's surface temperature) : 260°C or below Time at maximum temperature : 10 s or less Time of temperature higher than 220°C : 60 s or less Preheating time at 160 to 180°C : 60 to 120 s Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (Mass percentage) : 0.2% or less

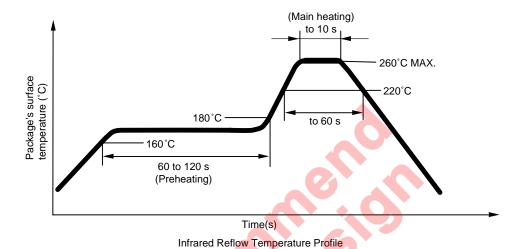


Figure 2 The example of the Mounting Pad

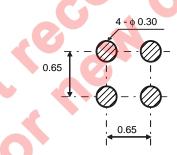
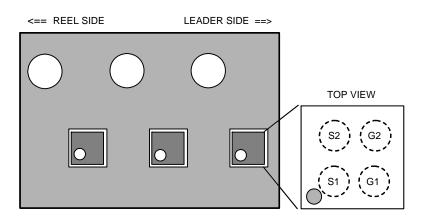


Figure 3 The unit orientation



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NEC μ PA2352

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